

# Energy Efficient Design and Energy Harvesting for Energy Autonomous Systems

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**Abstract**— Energy autonomy enabled by the energy efficient design and the energy harvesting is the one of the top requirements for maintenance-free IoT sensor nodes and wearable/implanted devices. In this paper, energy efficient ultra-low voltage ( $< 0.5V$ ) circuits are shown. Energy autonomous wearable healthcare devices using the flexible, large-area, and distributed organic electronics are also shown.

## I. INTRODUCTION

Requirements for IoT sensor nodes, wearable healthcare devices, and implanted medical devices are the wearing-unconsciousness and the maintenance-free operation as shown in Fig.1. To enable the wearing-unconsciousness, mechanically flexible or small-size devices with the wireless connection are required. To enable the maintenance-free operation, energy autonomous devices are required. The energy autonomy is achieved by both the energy efficient operation and the energy harvesting. In this paper, energy autonomous systems with the energy efficient design and the energy harvesting are shown.

## II. ENERGY EFFICIENT DESIGN

The energy efficient operation is achieved by a near-threshold operation and a temporal-spatial fine-grained control. Fig. 2 shows the simulated power supply voltage ( $V_{DD}$ ) dependence of power, delay, and energy. Compared with the nominal operation at  $V_{DD} = 1.2V$ , the energy of the near-threshold operation at  $V_{DD} = 0.3V$  is reduced to one-tenth of that at  $V_{DD} = 1.2V$ . Fig. 3 shows the temporal-spatial fine-grained control [1]. In the conventional design, the clock frequency ( $f_{CLK}$ ),  $V_{DD}$ , and the threshold voltage ( $V_{TH}$ ) of transistors are common within a chip. In contrast, in the state-

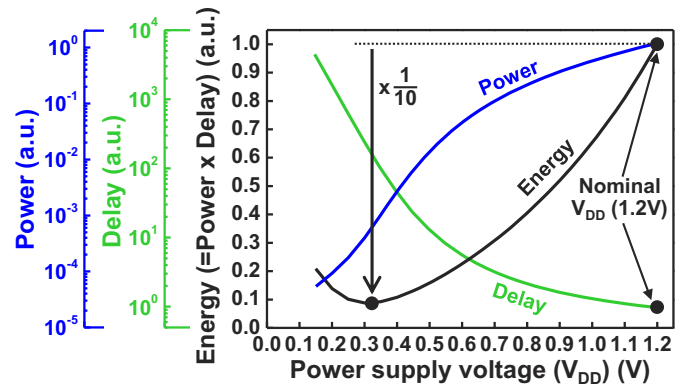


Fig. 2. Power supply voltage dependence of power, delay, and energy.

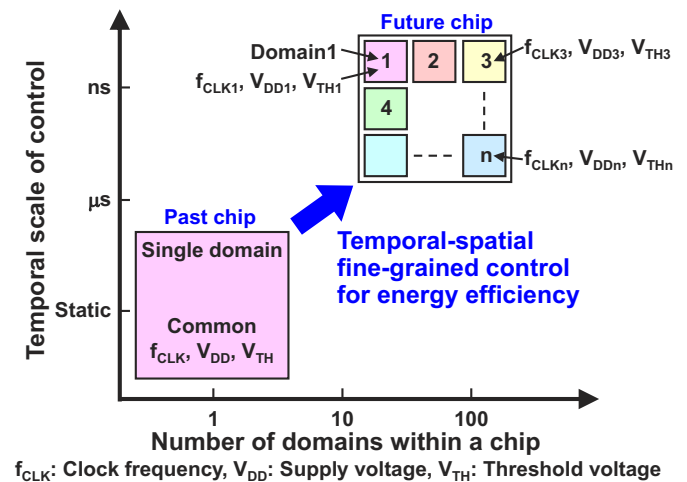


Fig. 3. Temporal-spatial fine-grained control.

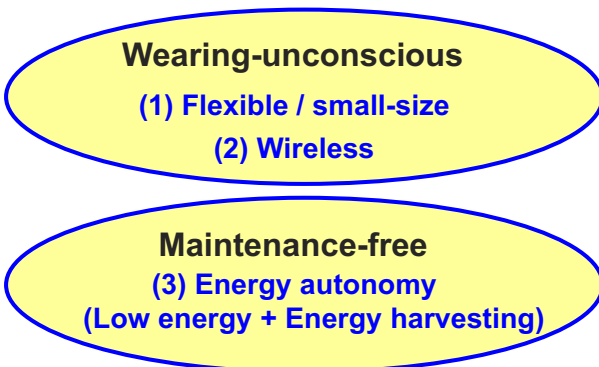
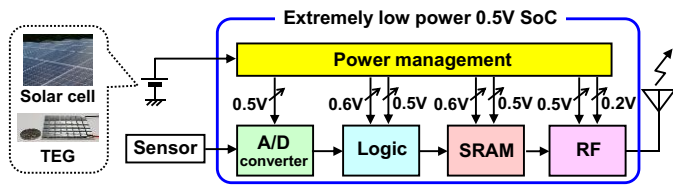


Fig. 1. Requirements for wearable/implanted devices.

of-the-art design, many different  $f_{CLK}$ 's,  $V_{DD}$ 's, and  $V_{TH}$ 's are used within a chip and they are dynamically changed to minimize the energy. Such temporal-spatial fine-grained control includes the dynamic voltage scaling [2], the dynamic frequency scaling [3], the power gating, the clock gating, the body biasing, the local gate overdrive [4], and the quick wake-up circuits [5].

Fig. 4 shows a block diagram of extremely low power 0.5V SoC for IoT sensor nodes. The voltage obtained from the energy harvester is regulated by the power management circuits [6-7] and many different  $V_{DD}$ 's are given to A/D



TEG: Thermoelectric generator

Fig. 4. Block diagram of extremely low power 0.5V SoC for IoT sensor nodes.

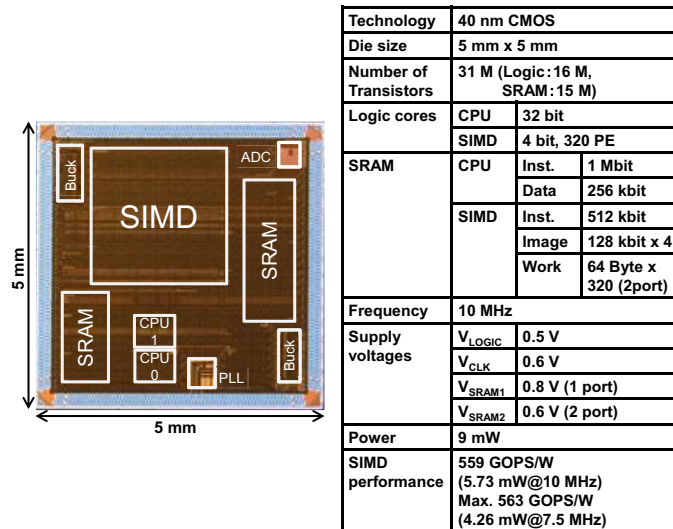


Fig. 5. 0.5V image processor [3].

converter, logic circuits, SRAM, and RF circuits for the temporal-spatial fine-grained control to minimize the energy. Fig. 5 shows an example of 0.5V SoC [3]. The 0.5V image processor with 563 GOPS/W SIMD and 32bit CPU includes an all digital PLL (ADPLL), an A/D converter, and buck converters.

### III. ENERGY AUTONOMOUS WEARABLE FLEXIBLE DEVICES

The organic electronics enables flexible, large-area, and distributed sensor and/or actuator array and is suitable for the wearing-unconscious devices. Several energy autonomous wearable healthcare devices using the organic electronics have been proposed [8-9].

Fig. 6 shows a photograph of a fever alarm armband (FAA) [10] integrating fully flexible solar cells, a piezoelectric speaker, a temperature detector, and 12V organic complementary FET circuits. FAA is a flexible energy autonomous healthcare device with the wireless interface. FAA is looped around an upper arm of a patient in a hospital room, and the temperature detector monitors the underarm temperature of the patient. 220- $\mu\text{m}$  thickness amorphous silicon solar cells attached outside of the upper arm generate the power. When high fever is detected, a 52- $\mu\text{m}$  thickness piezoelectric speaker with polyvinylidene difluoride (PVDF) makes a sound to alarm a nurse. Organic circuits and the temperature detector are fabricated on a 50- $\mu\text{m}$  thickness flexible polyimide film, and the solar cells and the speaker are attached on it. Fig. 7 shows a block diagram of FAA. An active

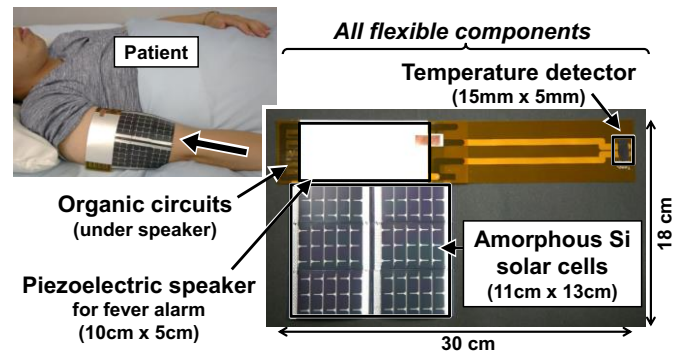


Fig. 6. Fever alarm armband [10].

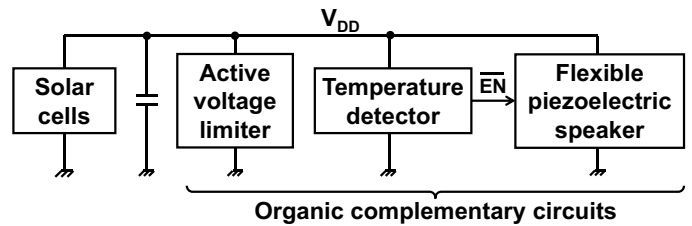


Fig. 7. Block diagram of fever alarm armband [10].

voltage limiter regulates  $V_{\text{DD}}$ . When the measured temperature is higher than the preset threshold temperature, a ring oscillator starts oscillation and the speaker makes a sound.

### ACKNOWLEDGMENT

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